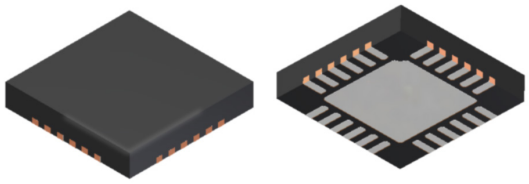
3-Phase Brushless DC Motor Pre-Driver

FEATURES AND BENEFITS

- Drives 6 N-channel MOSFETs
- Synchronous rectification for low power dissipation
- Internal UVLO and thermal shutdown circuitry
- Hall element inputs
- PWM current limiting
- Dead time protection
- FG outputs
- Standby mode
- Lock detect protection
- Overvoltage protection

PACKAGE: 28-contact QFN (ET package)



Not to scale

DESCRIPTION

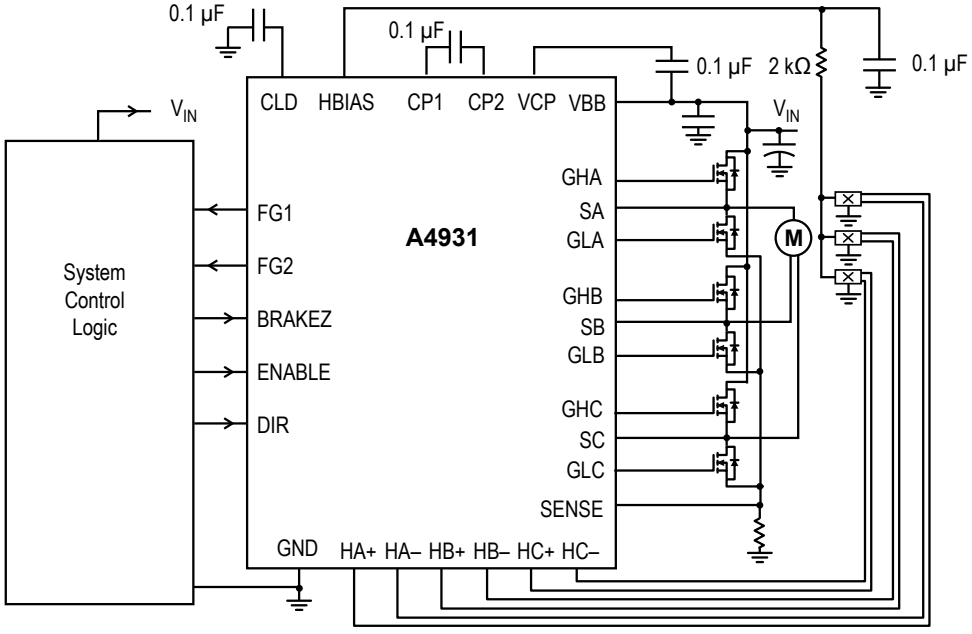
The A4931 is a complete 3-phase brushless DC motor pre-driver. The device is capable of driving a wide range of N-channel power MOSFETs and can support motor supply voltages up to 30 V. Commutation logic is determined by three Hall-element inputs spaced at 120°.

Other features include fixed off-time pulse-width modulation (PWM) current control for limiting inrush current, locked-rotor protection with adjustable delay, thermal shutdown, overvoltage monitor, and synchronous rectification. Internal synchronous rectification reduces power dissipation by turning on the appropriate MOSFETs during current decay, thus shorting the body diode with the low $R_{DS(on)}$ MOSFET. Overvoltage protection disables synchronous rectification when the motor pumps the supply voltage beyond the overvoltage threshold during current recirculation.

The A4931 offers enable, direction, and brake inputs that can control current using either phase or enable chopping. Logic outputs FG1 and FG2 can be used to accurately measure motor rotation. Output signals toggle state during Hall transitions, providing an accurate speed output to a microcontroller or speed control circuit.

The A4931 is supplied in a 5 mm × 5 mm, 28-terminal QFN package with exposed thermal pad. This small footprint package is lead (Pb) free with 100% matte-tin leadframe plating.

Typical Application



SELECTION GUIDE

Part Number	Packing	Package	Operating Ambient Temperature, T_A (°C)
A4931METTR-T	1500 pieces per reel	5 mm × 5 mm, 0.90 mm nominal height QFN	–20 to 105
A4931GETTR-T	1500 pieces per reel	5 mm × 5 mm, 0.90 mm nominal height QFN	–40 to 105

ABSOLUTE MAXIMUM RATINGS

Characteristic	Symbol	Notes	Rating	Units
Load Supply Voltage	V_{BB}		38	V
Motor Phase Output	S_X	t_w < 500 ns	–3	V
Hall Input	V_{Hx}	DC	–0.3 to 7	V
Logic Input Voltage Range	V_{IN}		–0.3 to 7	V
Logic Output Voltage Range	V_{FG}	FG1, FG2 pins	–0.3 to 7	V
Operating Ambient Temperature	T_A	Range M	–20 to 105	°C
		Range G	–40 to 105	°C
Maximum Junction Temperature	T_J(max)		150	°C
Storage Temperature	T_{stg}		–40 to 150	°C

THERMAL CHARACTERISTICS

Characteristic	Symbol	Test Conditions*	Rating	Units
Package Thermal Resistance, Junction to Ambient	$R_{\theta JA}$	4-layer PCB based on JEDEC standard	32	°C/W
Package Thermal Resistance, Junction to Exposed Pad	$R_{\theta JP}$		2	°C/W

*For additional information, refer to the Allegro website.

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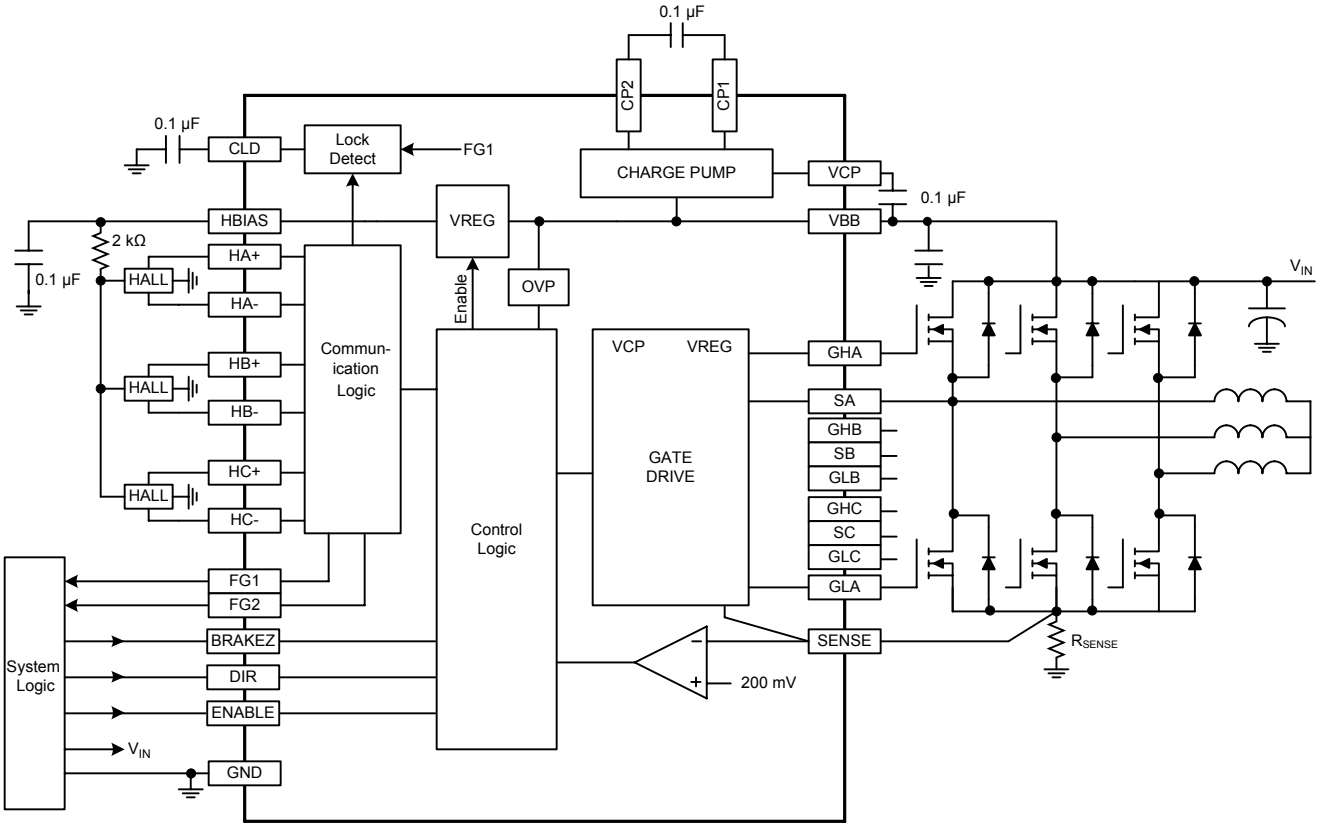
FUNCTIONAL BLOCK DIAGRAM



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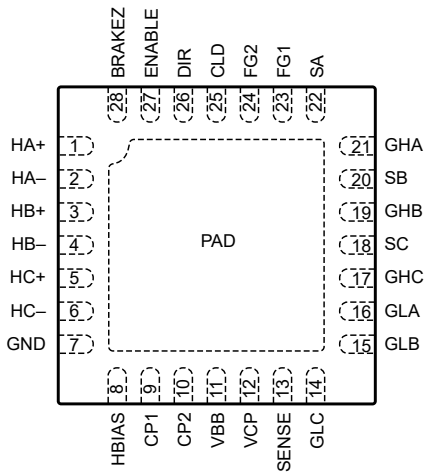
PINOUT DIAGRAM AND TERMINAL LIST



ET Package Pinout Diagram

Terminal List

Number	Name	Description
1	HA+	Hall input A
2	HA -	Hall input A
3	HB+	Hall input B
4	HB -	Hall input B
5	HC+	Hall input C
6	HC-	Hall input C
7	GND	Ground
8	HBIAS	Hall bias power supply output
9	CP1	Charge pump capacitor terminal
10	CP2	Charge pump capacitor terminal
11	VBB	Supply voltage
12	VCP	Reservoir capacitor terminal
13	SENSE	Sense resistor connection
14	GLC	Low side gate drive C

Number	Name	Description
15	GLB	Low side gate drive B
16	GLA	Low side gate drive A
17	GHC	High side gate drive C
18	SC	High side source connection C
19	GHB	High side gate drive B
20	SB	High side source connection B
21	GHA	High side gate drive A
22	SA	High side source connection A
23	FG1	FG 1 speed control output (3 Φ inputs)
24	FG2	FG 2 speed control output (ΦA input)
25	CLD	Locked rotor detect timing capacitor
26	DIR	Logic input – motor direction
27	ENABLE	Logic input – external PWM control
28	BRAKEZ	Logic input – motor brake (active low)

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ELECTRICAL CHARACTERISTICS*: Valid at T_A= 25°C, V_{BB} = 24 V, unless noted otherwise

Characteristics	Symbol	Test Conditions	Min.	Typ.	Max.	Units
Supply Voltage Range	V_{BB}	Operating	8	–	V_{BBOV}	V
Motor Supply Current	I_{BB}	f_{PWM} < 30 kHz, C_{LOAD} = 1000 pF	–	5	6	mA
		Charge pump on, outputs disabled, Standby mode	–	3	3.5	mA
HBIAS Voltage	V_{HBIAS}	0 mA ≤ I_{HBIAS} ≤ 24 mA	7.2	7.5	7.8	V
HBIAS Current Limit	$I_{HBIASlim}$		30	–	–	mA
CONTROL LOGIC						
Logic Input Voltage	$V_{IN(1)}$		2	–	–	V
	$V_{IN(0)}$		–	–	0.8	V
Logic Input Current	$I_{IN(1)}$	V_{IN} = 2 V	–1	<1.0	1	µA
	$I_{IN(0)}$	V_{IN} = 0.8 V	–1	<–1.0	1	µA
Input Pin Glitch Reject	t_{GLITCH}	ENB pin	350	500	650	ns
		DIR, BRAKEZ pins	700	1000	1300	ns
ENB Standby Pulse Propagation Delay	t_{dENB}	To outputs off	2.1	3	3.9	ms
HBIAS Wake-Up Delay, Standby Mode	t_{dHBIAS}	C_{HBIAS} = 0.1 µF	–	15	25	µs
GATE DRIVE						
High-Side Gate Drive Output	$V_{GS(H)}$	Relative to V_{BB}, I_{GATE} = 2 mA	7	–	–	V
Low-Side Gate Drive Output	$V_{GS(L)}$	I_{GATE} = 2 mA	7	–	–	V
Gate Drive Current (Sourcing)	I_{Gate}	V_{GH} = V_{GL} = 4 V	20	30	–	mA
Gate Drive Pull Down Resistance	R_{Gate}		10	28	40	Ω
Dead Time	t_{dead}		700	1000	1300	ns
Current Limit Input Threshold	V_{REF}		180	200	220	mV
Fixed Off-Time	t_{OFF}		18	25	37	µs
PROTECTION						
Thermal Shutdown Temperature	T_{JTSD}		155	170	185	°C
Thermal Shutdown Hysteresis	$T_{JTSDhys}$		14	15	26	°C
VBB UVLO Enable Threshold	V_{BBUV}	Rising V_{BB}	6.2	7	7.85	V
VBB UVLO Hysteresis	$V_{BBUVhys}$		0.4	0.75	1	V
VCP UVLO	V_{CPUV}	Relative to V_{BB}	4.6	–	6	V
Lock Detect Duration	t_{lock}	C = 0.1 µF	1.5	2	2.5	s
VBB Overvoltage Threshold	V_{BBOV}	Rising V_{BB}	30	33	37.5	V

Continued on the next page...

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ELECTRICAL CHARACTERISTICS* (continued): Valid at T_A= 25°C, V_{BB} = 24 V, unless noted otherwise

Characteristics	Symbol	Test Conditions	Min.	Typ.	Max.	Units
HALL LOGIC						
Hall Input Current	I_{HALL}	V_{IN} = 0.2 to 3.5 V	–1	0	1	µA
Common Mode Input Range	V_{CMR}		0.2	–	3.5	V
AC Input Voltage Range	V_{HALL}		60	–	–	mV_{p-p}
Hall Thresholds	V_{th}	Difference between Hall inputs at transitions	–	±10	–	mV
Hall Threshold Hysteresis	V_{HYS}	T_J = 25°C	10	20	30	mV
		T_J = –20°C to 125°C	5	20	40	mV
Pulse Reject Filter	t_{pulse}		–	2	–	µs
FG						
FG Output Saturation Voltage	$V_{FG(sat)}$	I_{FG} = 2 mA	–	–	0.5	V
FG Leakage Current	I_{FGlkg}	V_{FG} = 5 V	–	–	1	µA

*Typical data are for initial design estimations only, and assume optimum manufacturing and application conditions. Performance may vary for individual units, within the specified maximum and minimum limits.
For input and output current specifications, negative current is defined as coming out of (sourcing) the specified device pin.
Specifications throughout the allowed operating temperature range are guaranteed by design and characterization.

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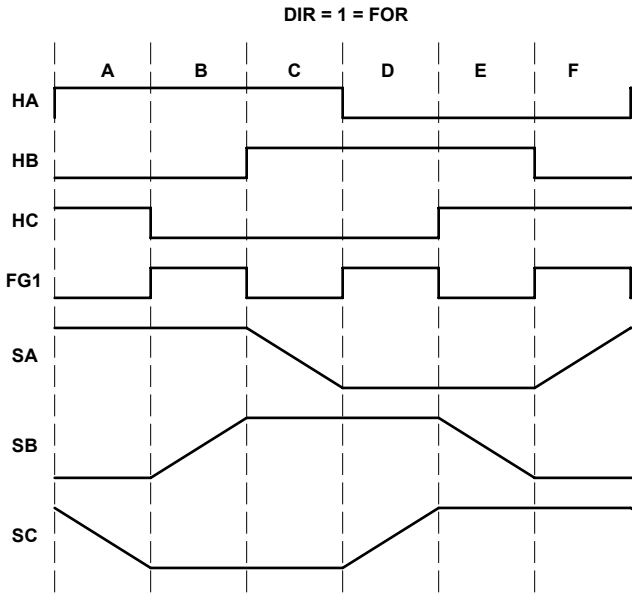
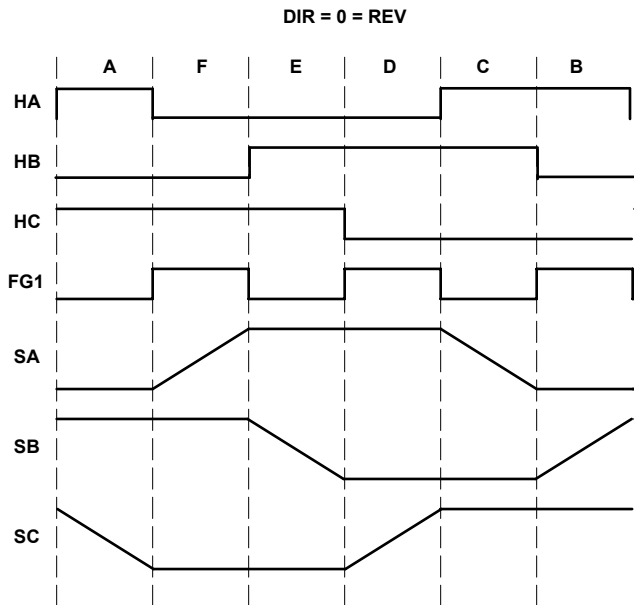
Logic States Table (See timing charts, below) X = Don't Care, Z = high impedance

Condition		Inputs					Resulting Pre-Driver Outputs						Motor Output		
		HA	HB	HC	BRAKEZ	ENB	GHA	GLA	GHB	GLB	GHC	GLC	A	B	C
DIR = 1 (Forward)	A	+	–	+	HI	LO	HI	LO	LO	HI	LO	LO	HI	LO	Z
	B	+	–	–	HI	LO	HI	LO	LO	LO	LO	HI	HI	Z	LO
	C	+	+	–	HI	LO	LO	LO	HI	LO	LO	HI	Z	HI	LO
	D	–	+	–	HI	LO	LO	HI	HI	LO	LO	LO	LO	HI	Z
	E	–	+	+	HI	LO	LO	HI	LO	LO	HI	LO	LO	Z	HI
	F	–	–	+	HI	LO	LO	LO	LO	HI	HI	LO	Z	LO	HI
DIR = 0 (Reverse)	A	+	–	+	HI	LO	LO	HI	HI	LO	LO	LO	LO	HI	Z
	F	–	–	+	HI	LO	LO	LO	HI	LO	LO	HI	Z	HI	LO
	E	–	+	+	HI	LO	HI	LO	LO	LO	LO	HI	HI	Z	LO
	D	–	+	–	HI	LO	HI	LO	LO	HI	LO	LO	HI	LO	Z
	C	+	+	–	HI	LO	LO	LO	LO	HI	HI	LO	Z	LO	HI
	B	+	–	–	HI	LO	LO	HI	LO	LO	HI	LO	LO	Z	HI
Fault*		+	+	+	HI	X	LO	LO	LO	LO	LO	LO	Z	Z	Z
Fault*		–	–	–	HI	X	LO	LO	LO	LO	LO	LO	Z	Z	Z
Brake*		X	X	X	LO	X	LO	HI	LO	HI	LO	HI	LO	LO	LO

* DIR = Don't Care





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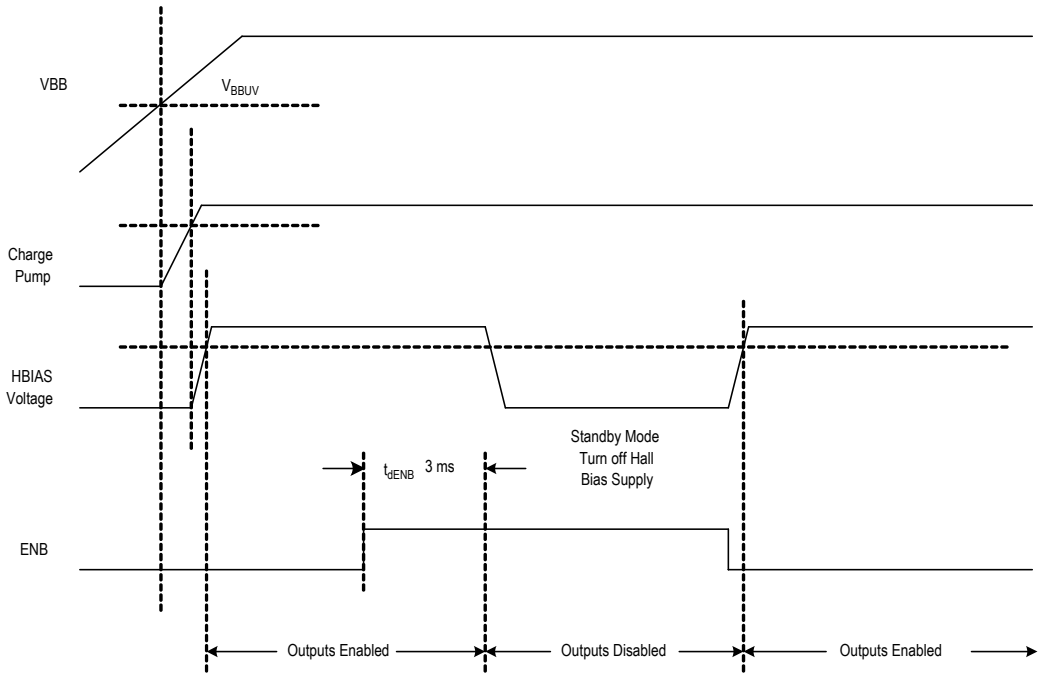

Figure 1: Power-Up and Standby Modes Timing Diagram

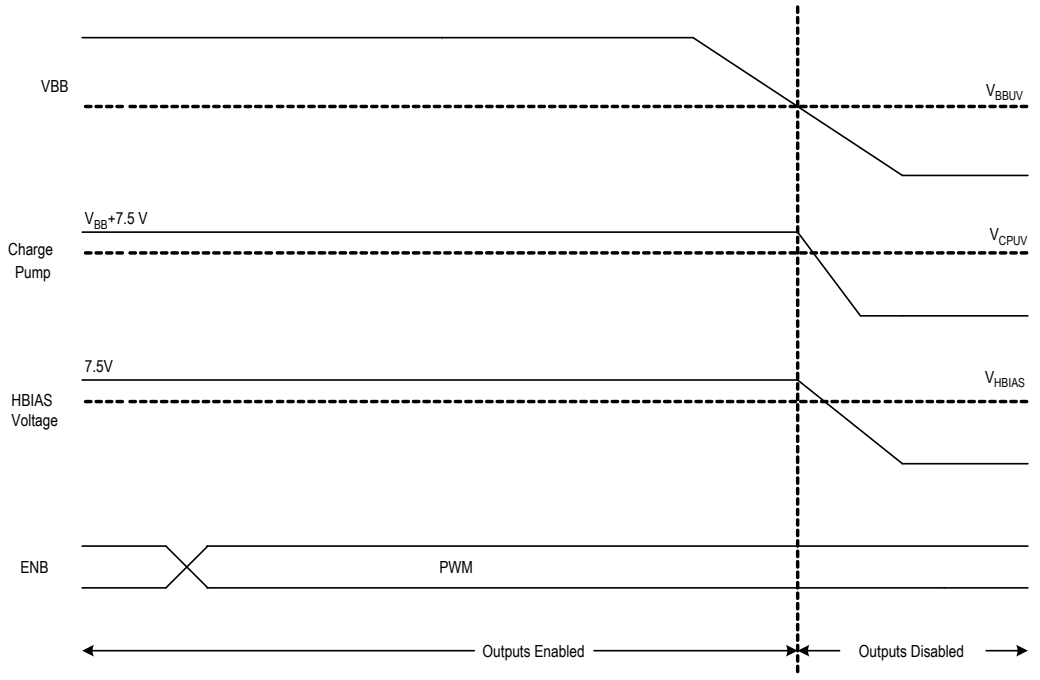

Figure 2: Power-Down Timing Diagram

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FUNCTIONAL DESCRIPTION

Current Regulation

Load current is regulated by an internal fixed off-time PWM control circuit. When the outputs of the full bridge are turned on, current increases in the motor winding until it reaches a value, I_{TRIP}, given by:

$$I_{TRIP} = 200 \text{ mV} / R_{SENSE} .$$

When I_{TRIP} is reached, the sense comparator resets the source enable latch, turning off the source driver. At this point, load inductance causes the current to recirculate for the fixed off-time period.

Enable Logic

The Enable input terminal (ENB pin) allows external PWM. ENB low turns on the selected sink-source pair. ENB high switches off the appropriate drivers and the load current decays. If ENB is held low, the current will rise until it reaches the level set by the internal current control circuit. Typically PWM frequency is in 20 to 30 kHz range. If the ENB high pulse width exceeds 3 ms, the gate outputs are disabled. The Enable logic is summarized in the following table:

ENB Pin Setting	Outputs	Outputs State
0	On	Drive
1	Source Chopped	Slow Decay with Synchronous Rectification
1 for > 3 ms typical	Off	Disable

Fixed Off-Time

The A4931 fixed off-time is set to 25 µs nominal.

PWM Blank Timer

When a source driver turns on, a current spike occurs due to the reverse recovery currents of the clamp diodes as well as switching transients related to distributed capacitance in the load. To prevent this current spike from erroneously resetting the source Enable latch, the sense comparator is blanked. The blanking timer runs after the off-time counter completes, in order to provide the blanking function. The blanking timer is reset when ENB is chopped or DIR is changed. With external PWM control, a DIR change or an ENB on triggers the blanking function. The duration is fixed at 1.5 µs.

Synchronous Rectification

When a PWM-off cycle is triggered, either by a chop command on ENB or by an internal fixed off-time cycle, load current recirculates. The A4931 synchronous rectification feature turns on the appropriate MOSFETs during the current decay, and effectively shorts out the body diodes with the low $R_{DS(on)}$ driver. This lowers power dissipation significantly and can eliminate the need for external Schottky diodes.

Brake Mode

A logic low on the BRAKEZ pin activates Brake mode. A logic high allows normal operation. Braking turns on all three sink drivers, effectively shorting out the motor-generated BEMF. The BRAKEZ input overrides the ENB input and also the Lock Detect function.

It is important to note that the internal PWM current control circuit does not limit the current when braking, because the current does not flow through the sense resistor. The maximum current can be approximated by V_{BEMF} / R_{LOAD}. Care should be taken to insure that the maximum ratings of the A4391 are not exceeded in the worse case braking situation, high speed and high inertial load.

HBIAS Function

This function provides a power supply of 7.5 V, current-limited to 30 mA. This reference voltage is used to power the logic sections of the IC and also to power the external Hall elements.

Standby Mode

To prevent excessive power dissipation due to the current draw of the external Hall elements, Standby mode turns off the HBIAS output voltage. Standby mode is triggered by holding ENB high for longer than 3 ms. Note that Brake mode overrides Standby mode, so hold the BRAKEZ pin high in order to enter Standby mode.

Charge Pump

The internal charge pump is used to generate a supply above V_{BB} to drive the high-side MOSFETs. The voltage on the VCP pin is internally monitored, and in case of a fault condition, the outputs of the device are disabled.

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Fault Shutdown

In the event of a fault due to excessive junction temperature or due to low voltage on VCP or VBB, the outputs of the device are disabled until the fault condition is removed. At power-up, the UVLO circuit disables the drivers.

Overvoltage Protection

VBB is monitored to determine if a hazardous voltage is present due to the motor generator pumping up the supply bus. When the voltage exceeds V_{BBOV}, the synchronous rectification feature is disabled.

Overtemperature Protection

If die temperature exceeds approximately 170°C, the Thermal Shutdown function will disable the outputs until the internal temperature falls below the 15°C hysteresis.

Hall State Reporting

The FG1 pin is an open-drain output that changes state at each transition of an external Hall element. The FG2 pin is an open-drain output that changes state at each HAx transition.

Lock Detect Function

The IC will evaluate a locked rotor condition under either of these two different conditions:

• The FG1 signal is not consistently changing.

• The proper commutation sequence is not being followed. The motor can be locked in a condition in which it toggles between two specific Hall device states.

Both of these fault conditions are allowed to persist for period of time, t_{lock}. t_{lock} is set by capacitor connected to CLD pin. C_{LD} produces a triangle waveform (1.67 V peak-to-peak) with frequency linearly related to the capacitor value. t_{lock} is defined as 127 cycles of this triangle waveform, or:

$$t_{lock} = C_{LD} \times 20 \text{ s}/\mu\text{F}$$

After the wait time, t_{lock} , has expired, the outputs are disabled, and the fault is latched. These fault conditions can only be cleared by any one of the following actions:

• Rising or falling edge on the DIR pin

• VBB UVLO threshold exceeded (during power-up cycle)

• ENB pin held high for > t_{lock} / 2

The Lock Detect function can be disabled by connecting CLD to GND.

When the A4931 is in Brake mode, the Lock Detect counter is disabled.

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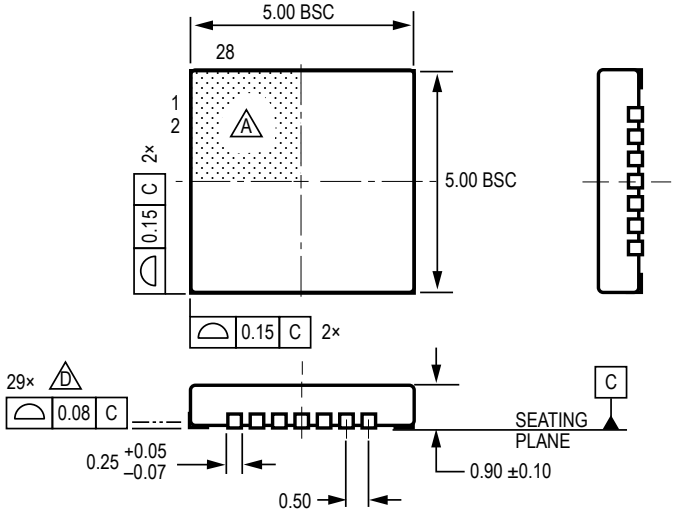
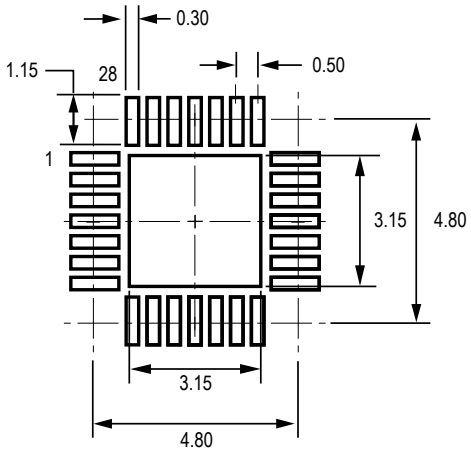
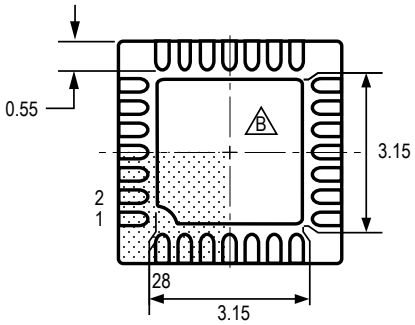
ET Package, 28-Contact QFN





C PCB Layout Reference View

Contact the factory for the sidewall plating PCB footprint and assembly instructions.



E Standard Branding Reference View 1

Line 1: Part Number
Line 2: Logo A, 4-Digit Date Code
Line 3: Characters 5, 6, 7, 8 of Assembly Lot Number

For Reference Only; not for tooling use
(reference DWG-0000378, Rev. 3)
Dimensions in millimeters
Exact case and lead configuration at supplier discretion within limits shown

A Terminal #1 mark area

B Exposed thermal pad (reference only, terminal #1 identifier appearance at supplier discretion)

C Reference land pattern layout (reference IPC7351 QFN50P500X500X100-29V1M);
All pads a minimum of 0.20 mm from all adjacent pads; adjust as necessary to meet application process requirements and PCB layout tolerances; when mounting on a multilayer PCB, thermal vias at the exposed thermal pad land can improve thermal dissipation (reference EIA/JEDEC Standard JESD51-5)

D Coplanarity includes exposed thermal pad and terminals

E Branding scale and appearance at supplier discretion

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Revision History

Number	Date	Description
8	February 10, 2020	Added G temperature rated part option; minor editorial updates
9	February 10, 2022	Updated package drawing (page 11)

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